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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/893,976	06/29/2001	Ik Soo kim	8733.437.00	6152
30827	7590 10/27/2003	EXAMINER		
	LONG & ALDRIDGE	KIELIN,	ERIK J	
1900 K STREET, NW WASHINGTON, DC 20006			ART UNIT	PAPER NUMBER
	,		2813	

DATE MAILED: 10/27/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

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# Office Action Summary

Application No.	Applicant(s)			
09/893,976	KIM, IK SOO			
Examiner	Art Unit			
Erik Kielin	2813			
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-- The MAILING DATE of this communication appears on the cover sheet with the correspond Period for Reply

THE M - Extens after S - If the p - If NO p - Failure - Any rep	RTENED STATUTORY PERIOD F AILING DATE OF THIS COMMUN ions of time may be available under the provision X (6) MONTHS from the mailing date of this come riod for reply specified above is less than thirty ( eriod for reply is specified above, the maximum s to reply within the set or extended period for repl ily received by the Office later than three months patent term adjustment. See 37 CFR 1.704(b).	IICATION s of 37 CFR 1 munication. 30) days, a re tatutory period y will, by statu	l. 1.136(a). In no ever eply within the statut d will apply and will ate, cause the appli	nt, however tory mining expire S cation to	ver, may a reply be timely filed mum of thirty (30) days will be considered timely. EIX (6) MONTHS from the mailing date of this communication. become ABANDONED (35 U.S.C. § 133).		
Status	patent term adjustment. See 37 CFA 1.704(b).						
1)⊠	Responsive to communication(s) f	iled on <u>28</u>	3 July 2003 .				
2a)⊠	This action is <b>FINAL</b> .	2b)□ T	This action is i	non-fir	nal.		
•	Since this application is in condition closed in accordance with the practice of Claims				mal matters, prosecution as to the merits is 1935 C.D. 11, 453 O.G. 213.		
·		ro nondin	a in the applic	nation			
-	Claim(s) <u>1,3-7,9-11 and 13-22</u> is/a	· ·					
	a) Of the above claim(s) <u>21-22</u> is/a	ile williara	awii iioiii con	Siuera	uon.		
	5) Claim(s) is/are allowed.						
	6)⊠ Claim(s) <u>1,3-7,9-11 and 13-20</u> is/are rejected.						
·	Claim(s) is/are objected to.		lan alaatian na		n ant		
Applicatio	Claim(s) are subject to restri	ction and/	or election re	quiren	nent.		
	ne specification is objected to by the	e Evamin	ner				
·	ne drawing(s) filed on is/are			obiecte	ed to by the Examiner		
10/1	Applicant may not request that any ob	-		-	-		
11)□ TI	• • • • • • • • • • • • • • • • • • • •	-			d b) disapproved by the Examiner.		
,	If approved, corrected drawings are re						
12)∐ TI	ne oath or declaration is objected t	•					
Priority un	der 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
a) All b) Some * c) None of:							
1	1. Certified copies of the priority documents have been received.						
2	2. Certified copies of the priority documents have been received in Application No						
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.							
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
a) The translation of the foreign language provisional application has been received.							
15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.							
Attachment(s	3)						
2) Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review ( ation Disclosure Statement(s) (PTO-1449) I			5) 🔲	Interview Summary (PTO-413) Paper No(s)  Notice of Informal Patent Application (PTO-152)  Other:		

U.S. Patent and Trademark Office PTOL-326 (Rev. 04-01)

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### **DETAILED ACTION**

This action responds to the Amendment filed 28 July 2003, Paper no. 8.

#### Election/Restrictions

1. Newly submitted claims 21 and 22 are directed to an invention that is independent or distinct from the invention originally claimed for the following reasons:

The original claims were drawn to a species of LCD having an "S"-shaped channel formed in part over the gate electrode. The new claims 21 and 22 are drawn to an LCS having the gap between the source/drain electrodes formed entirely over the gate electrode.

Since applicant has received an action on the merits for the originally presented invention, this invention has been constructively elected by original presentation for prosecution on the merits. Accordingly, claims 21 and 22 are withdrawn from consideration as being directed to a non-elected invention. See 37 CFR 1.142(b) and MPEP § 821.03.

## Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1, 3-7, 9, 10 and 11, 13-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's admitted prior art (APA) in view of JP 2-58030 A (Taniguchi et al.).

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Regarding claims 1 and 11, **Taniguchi** discloses a liquid crystal display device and method of manufacturing the device comprising forming each of the following:

a gate electrode 6 on a substrate 1; a gate insulating film 12 on the substrate 1 and over the gate electrode 6; a semiconductor layer 14 on the gate insulating film 12 and over the gate electrode 6; a source electrode 8 and a drain electrode 10 on the semiconductor layer 14 and adjacent the gate electrode 6, wherein the source and drain electrodes oppose each other; a protective layer 18 on the gate insulating film 12 and over the source and drain electrodes 8, 10; and a pixel electrode 22 on the protective layer 18. (See instant specification, paragraphs [0003]-[0013] and Figs. 1 through 3E.)

APA does not teach that the source electrode and the drain electrode each include at least one protrusion that extends toward the other electrode and that the channel has and "2"-shape wherein an entire area of the channel is formed over the gate electrode.

Taniguchi teaches a liquid crystal display and method of manufacturing the display wherein the source electrode SD2 and the drain electrode SD1 each include at least one protrusion d1 that extends toward the other electrode in order to beneficially increase the channel width of the transistor, thereby creating a "2"-shaped channel having an entire area of the channel formed over the gate electrode. (See Abstract and Figs. 1 and 2.)

It would have been obvious for one of ordinary skill in the art, at the time of the invention to use the source/drain electrodes having protrusions and the consequent "2"-shaped channel having an area formed entirely over the gate electrode as the source/drain electrodes of APA in order to beneficially increase the channel width of the transistor, which enables reduction of the TFT size and improves the aperture rate, as taught by **Taniguchi** (Abstract.)

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Regarding claims 3 and 13, APA discloses the active layer 14 on the gate insulating film 12; and the ohmic contact layer 16 on the active layer 14.

Regarding claims 4 and 14, APA teaches that the ohmic contact layer 16 contains an opening corresponding to the channel 24 (Fig. 3C; paragraph [0009] --especially the last two sentences), but does not teach that the channel is "2"-shaped.

**Taniguchi** shows that the channel is "2"-shaped.

It would have been obvious for one of ordinary skill in the art, at the time of the invention to use a "2"-shaped channel as the channel of APA to increase the channel width as taught by Taniguchi.

Regarding claims 5, 6, 15, and 16, **APA** discloses that the active layer is undoped silicon and the ohmic contact layer is doped silicon (instant specification, p. 4, paragraph [0008]).

Regarding claims 7 and 17, the **APA** discloses that standard channel width is about 25  $\mu m$  (instant specification, p. 3, paragraph [0005]), but does not teach a channel width of greater than 50  $\mu m$ .

Tanaguchi does not indicate the width of the channel but indicates that the width should be increased. Also the Tanaguchi Fig. 1 shows that the channel width is more than doubled by comparing a source/drain electrodes without protrusions to those source/drain electrodes SD2, SD1, with protrusions d1 the same manner as presently proposed in the instant invention.

It would have been obvious for one of ordinary skill in the art, at the time of the invention to width the channel width of **APA** to greater than 50 µm by forming the protruding portions of the source/drain electrodes of **Tanaguchi** on those source/drain electrodes of **APA** because **Tanaguchi** teaches that the channel width should be longer than in the absence of such

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protrusions and shows geometrically that the width of the channel is more than doubled. Moreover, these claims are *prima facie* obvious without showing that the claimed ranges achieve unexpected results relative to the prior art range. *In re Woodruff*, 16 USPQ2d 1935, 1937 (Fed. Cir. 1990). See also *In re Huang*, 40 USPQ2d 1685, 1688(Fed. Cir. 1996)(claimed ranges of a result effective variable, which do not overlap the prior art ranges, are unpatentable unless they produce a new and unexpected result which is different in kind and not merely in degree from the results of the prior art). See also *In re Boesch*, 205 USPQ 215 (CCPA) (discovery of optimum value of result effective variable in known process is ordinarily within skill of art) and *In re Aller*, 105 USPQ 233 (CCPA 1955) (selection of optimum ranges within prior art general conditions is obvious). In the instant case, the result of forming the protrusions on the source/drain electrodes expectedly increases the channel width as clearly taught by **Tanaguchi**.

Regarding claim 18, APA discloses that the channel extends only over the gate electrode

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Regarding claims 9 and 19, APA discloses that the pixel electrode 22 contacts the drain electrode 10 through an opening 20 in the protective layer 18 (Fig. 3E).

Regarding claims 10 and 20, APA discloses that the data line 4 is in electrical communication with the source electrode 8 (Fig. 3E).

### Response to Arguments

4. Applicant's arguments filed 28 July 2003 (Paper no. 8) have been fully considered but they are not persuasive.

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Applicant argues that Tanaguchi does not teach the newly added feature to the claims of "wherein an entire area of the "2"-shaped channel is formed over the gate electrode. Examiner respectfully disagrees. The Tanaguchi figures very clearly show "an entire area" of the channel is formed over the gate electrode, which in no manner limits "the entire area" of the channel to be formed over the gate electrode. Moreover, the channel must overlie the gate electrode for the most part in order for the transistor to function, as is notoriously well known to one of ordinary skill. Nonetheless, the entire channel is formed over the gate electrode, as shown in the Tanaguchi figures. Applicant has not pointed out what portion of the channel somehow does not overlie the gate electrode.

Also note that the APA discloses that the entire channel is formed over the gate electrode, such that one of ordinary skill would form the channel entirely over the gate electrode. And finally, the is no indication in the specification that this geometry provides and unexpected result. Since the APA clearly shows that the channel is formed entirely over the gate electrode, it is incumbent upon Applicant to provide *evidence* that the presently claimed feature of a "2"-shpaed electrode formed entirely over the gate electrode provides some unexpected result. Finally it is noted that MPEP 2145 states that "argument does not replace evidence where evidence is necessary."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Erik Kielin whose telephone number is 703-306-5980. The examiner can normally be reached on 9:00 - 19:30 on Monday through Thursday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead, Jr., can be reached at 703-308-4940. The fax phone numbers for the

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organization where this application or proceeding is assigned are 703-872-9318 for regular

communications and 703-872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is 703-308-0956.

Erik Kielin

Primary Examiner

October 23, 2003